FST3306 2-Bit Low Power Bus Switch

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FST3306 2-Bit Low Power Bus Switch

General Description

The FST3306 is a 2-bit ultra high-speed CMOS FET bus switch with TTL-compatible active LOW control inputs. The low on resistance of the switch allows inputs to be connected to outputs with minimal propagation delay and without generating additional ground bounce noise. The device is organized as a 2-bit switch with independent bus enable (\overline{BE}) controls. When \overline{BE} is LOW, the switch is ON and Port A is connected to Port B. When \overline{BE} is HIGH, the switch is OPEN and a high-impedance state exists between the two ports. Control inputs tolerate voltages up to 5.5V independent of V_{CC}.

Features

- Typical 3Ω switch resistance at 5.0V V_{CC}
- Minimal propagation delay through the switch
- Power down high impedance input/output
- Zero bounce in flow through mode.
- TTL compatible active LOW control inputs
- Control inputs are overvoltage tolerant

Ordering Code:

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Order Number	Package Number	Package Description				
FST3306MTC MTC08 8-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide						
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.						

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Name	Description
A	Bus A
В	Bus B
BE	Bus Enable Input

Function Table

Bus Enable Input BE	Function		
L	B Connected to A		
Н	Disconnected		

H = HIGH Logic Level L = LOW Logic Level

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FST3306

Absolute Maximum Ratings(Note 1)

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Supply Voltage (V _{CC})	-0.5V to +7.0V
DC Switch Voltage (VS)	-0.5 V to $+7.0 V$
DC Output Voltage (VIN) (Note 2)	-0.5V to +7.0V
DC Input Diode Current	
(I _{IK}) V _{IN} < 0V	–50 mA
DC Output (I _{OUT}) Current	128 mA
DC V_{CC} or Ground Current (I _{CC} /GND)	±100 mA
Storage Temperature Range (T _{STG})	$-65^\circ C$ to $+150^\circ C$
Junction Lead Temperature under Bias (T _J)	+150°C
Lead Temperature (T _L)	
(Soldering, 10 seconds)	+260°C
Power Dissipation (P _D) @ +85°C	250 mW

Recommended Operating Conditions (Note 3)

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Supply Operating (V _{CC})	4.0V to 5.5V
Control Input Voltage (VIN)	0V to 5.5V
Switch Input Voltage (V _{IN})	0V to 5.5V
Output Voltage (V _{OUT})	0V to 5.5V
Operating Temperature (T _A)	-40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
Control Input	0 ns/V to 5 ns/V
Switch I/O	0 ns/V to DC
Thermal Resistance (θ_{JA})	250°C/W

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions

for actual device operation. **Note 2:** The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.

Note 3: Unused logic inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V _{CC}	T	_A = −40°C to +85	0°C to +85°C		Conditions
Symbol		(V)	Min	Тур		Units	Conditions
V _{IK}	Clamp Diode Voltage	4.5			-1.2	V	I _{IN} = -18 mA
V _{IH}	HIGH Level Input Voltage	4.0-5.5	2.0			V	
V _{IL}	LOW Level Input Voltage	4.0-5.5			0.8	V	
V _{ОН}	HIGH Level Output Voltage	4.5-5.5		see Figure 3		V	$V_{IN} = V_{CC}$
I _{IN}	Input Leakage Current	5.5			±1.0	μA	$0 \le V_{IN} \le 5.5V$
OFF	Switch OFF Leakage Current	5.5			±1.0	μA	$0 \le A, B, \le V_{CC}$
R _{ON}	Switch On Resistance	4.5		3	7		$V_{IN} = 0V, I_{IN} = 64 \text{ mA}$
	(Note 4)	4.5		3	7	Ω	$V_{IN} = 0V, I_{IN} = 30 \text{ mA}$
		4.5		6	15		$V_{IN} = 2.4V, I_{IN} = 15 \text{ mA}$
		4.0		10	20		$V_{IN} = 2.4V, I_{IN} = 15 \text{ mA}$
I _{CC}	Quiescent Supply Current	5.5			3	μΑ	$V_{IN} = V_{CC}$ or GND,
							$I_{OUT} = 0$
Δl _{CC}	Increase in I _{CC} per Input	5.5		1	2.5	mA	$V_{IN} = 3.4V, \ I_O = 0,$
	(Note 5)						Control Input Only

Note 4: Measured by the voltage drop between A and B pins at the indicated current through the switch. On resistance is determined by the lower of the voltages on the two (A or B) pins.

Note 5: Per TTL driven input (V $_{\rm IN}$ = 3.4V, control input only). A and B pins do not contribute to I $_{\rm CC.}$

	Parameter		$T_A = -40^{\circ}C$ to $+85^{\circ}C$				Conditions	
Symbol		V _{cc}	$\textbf{C}_{\textbf{L}}=\textbf{50}~\textbf{pF},~\textbf{RU}=\textbf{RD}=\textbf{500}\Omega$			Units		Figure Number
		(V)	Min	Тур	Max			
t _{PHL} , t _{PLH}	Prop Delay Bus to Bus (Note 6)	4.0-5.5			0.25	ns	V _I = OPEN	Figures 1, 2
t _{PZL} ,	Output Enable Time	4.5–5.5	0.8	2.5	4.2	ns	$V_I = 7V$ for t_{PZL}	Figures
t _{PZH}		4.0	0.8	3.0	4.6	115	$V_I = 0V$ for t_{PZH}	1, 2
t _{PLZ} ,	Output Disable Time	4.5–5.5	0.8	3.1	4.8	ns	$V_I = 7V$ for t_{PLZ}	Figures
t _{PHZ}		4.0	0.8	2.9	4.4	115	$V_I = 0V$ for t_{PHZ}	1, 2

Note 6: This parameter is guaranteed. The bus switch contributes no propagation delay other than the RC delay of the typical On resistance of the switch and the 50 pF load capacitance, when driven by an ideal voltage source (zero output impedance). The specified limit is calculated on this basis.

Capacitance

Symbol	Parameter	Тур	Max	Units	Conditions
CIN	Control Pin Input Capacitance	2.5		pF	$V_{CC} = 0V$
C _{I/O} (OFF)	Port OFF Capacitance	6		pF	$V_{CC} = 5.0V = \overline{BE}$
C _{I/O} (ON)	Switch ON Capacitance	12		pF	$V_{CC} = 5.0V, \overline{BE} = 0V$



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